



Infrared Laser Diode (Frame Type)

Features

• Wavelength: 790 nm (Typ.)

• Frame type

• Compact lightweight thin package

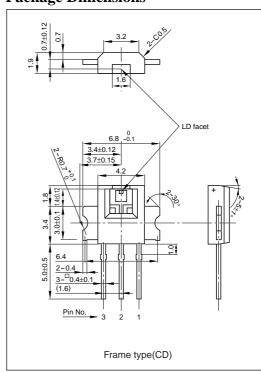
• Straight leads

Absolute Maximum Ratings at Tc=25°C (as per JISC 7032)

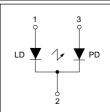
Parameter		Symbol	Condition	Ratings	Unit	
Light Output		Po	Kink free	5	mW	
Reverse Voltage	Laser	VR	-	2	V	
	PIN	VK	-	30	v	
Operating Temperature		Topr	1)	-10 to +70	°C	
Storage Temperature		Tstg	1)	-40 to +85	°C	
Soldering Temperature		Tsol	2)	260	°C	

- 1) Case temperature
- 2) Soldering Time≤3s, 1.6 mm from the root of a lead.

Package Dimensions



Pin Connection



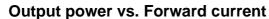
Electrical and Optical Characteristics 3) 4) at Tc=25°C

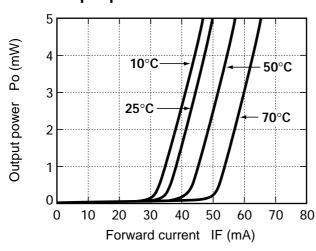
Parameter		Symbol	Condition	Min.	Тур.	Max.	Unit
Threshold Current		Ith	CW	-	35	50	mA
Operating Current		Iop	Po=3mW	=	45	60	mA
Operating Voltage		Vop	Po=3mW	-	1.8	2.3	V
Peak Lasing Wavelength 5)		λp	Po=3mW	-	790	805	nm
Light Output Power		Po	-	-	3	-	mW
Beam 6)	Perpendicular	$\theta \perp$	Po=3mW	25	35	45	0
Divergence	Parallel	θ //	Po=3mW	8	10.5	14	0
Off Axis	Perpendicular	$\Delta \; \theta \perp$	Po=3mW	-	-	±3	0
Angle	Parallel	$\Delta~\theta$ //	Po=3mW	=	=	±2	0
Differential Efficiency		dPo/dIop	Po=3mW	0.18	=	-	mW/mA
Monitoring Output Current		Im	Po=3mW	0.05	0.20	0.40	mA

- 3) Initial values 4) All the above values are evaluated with Tottori Sanyo's measuring apparatus
- 5) Wafer lot go/no-go decision criteria 6) Full angle at half maximum

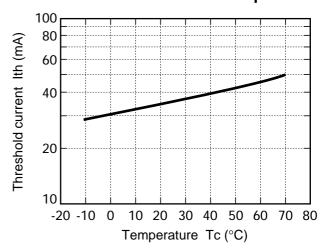
Note: The above product specification are subject to change without notice.

Characteristics

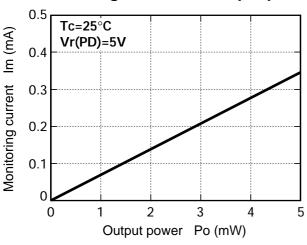




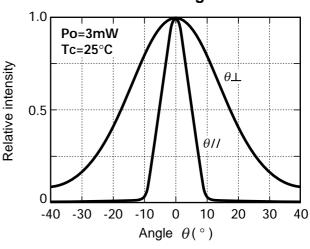
Threshold current vs. Temperature



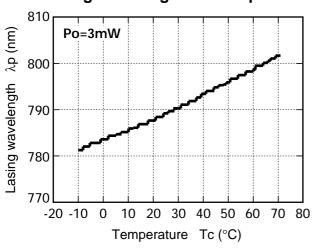
Monitoring current vs. Output power



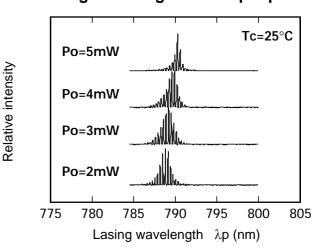
Beam divergence



Lasing wavelength vs. Temperature



Lasing wavelength vs. Output power





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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by; Tottori SANYO Electric Co., Ltd.

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